



S/N09/135413

PATENT

JAN 23 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al. Examiner: Viet Nguyen
Serial No.: 09/135413 Group Art Unit: 2818
Filed: August 14, 1998 Docket No: 303.354US2
Title: METHOD FOR OPERATING A MEMORY DEVICE HAVING AN
AMORPHOUS SILICON CARBIDE GATE INSULATOR (as amended)

PRELIMINARY AMENDMENT

MS RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Prior to taking up this application for examination, please enter the following
amendments:

IN THE TITLE

Please amend the title as follows:

METHOD FOR OPERATING A ~~DEAPROM~~ MEMORY DEVICE HAVING AN
AMORPHOUS SILICON CARBIDE GATE INSULATOR